



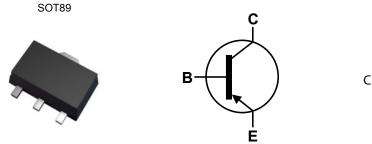
32V PNP MEDIUM POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > -32V
- I_C = -2A high Continuous Current
- Low saturation voltage V_{CE(sat)} < 800mV @ 2A
- Complementary NPN Type: 2DD1766
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

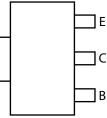
- Case: SOT89
- Case material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (approximate)



Top View



Device Symbol



Pin Out - Top View

Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
2DB1188P-13	P23P	13	12	2,500
2DB1188Q-13	P23Q	13	12	2,500
2DB1188Q-13R	P23Q	13	12	4,000
2DB1188R-13	P23R	13	12	2,500

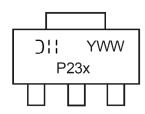
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free,"Green" and Lead-Free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



P23x = Product Type Marking Code Where P23P = 2DB1188P P23Q = 2DB1188Q P23R = 2DB1188R ⊃!! = Manufacturers' code marking YWW = Date Code Marking Y = Last Digit of Year (ex: 1 = 2011) WW = Week Code (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-32	V
Emitter-Base Voltage	V _{EBO}	-6	V
Continuous Collector Current	Ic	-2	А
Peak Pulse Collector Current	ICM	-3	A
Base Current	I _B	-500	mA

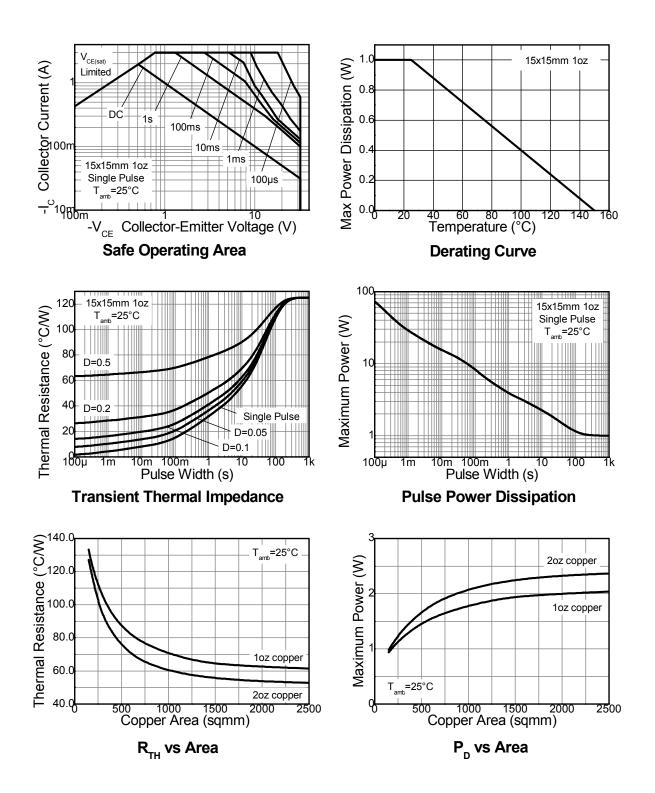
Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	1	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	125	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R _{θJL}	19	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 5. For a device surface mounted on 15mm x 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition. 6. Thermal resistance from junction to solder-point (on the exposed collector pad).



Thermal Characteristics and Derating Information

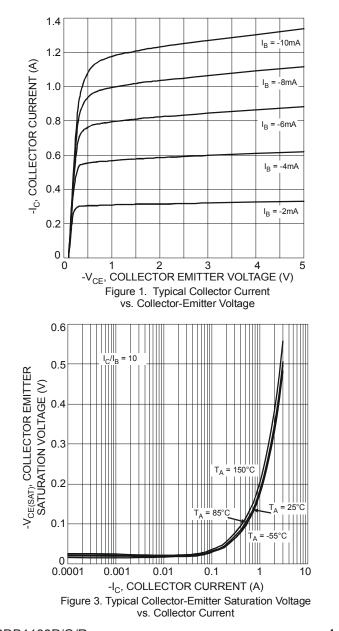


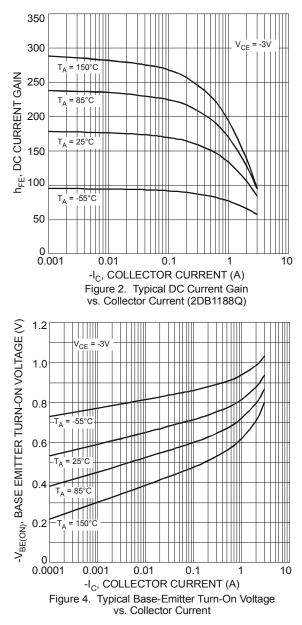


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Charac	teristic	Symbol	Min	Тур	Мах	Unit	Test Condition
OFF CHARACTERISTICS (N		- - ,					
Collector-Base Breakdown Voltage		BV _{CBO}	-40			V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage		BV _{CEO}	-32	_	_	V	I _C = -10mA, I _B = 0
Emitter-Base Breakdown Voltage		BV _{EBO}	-6	_	_	V	I _E = -100μA, I _C = 0
Collector Cutoff Current		I _{CBO}	_	_	-100	nA	$V_{CB} = -20V, I_E = 0$
Emitter Cutoff Current		I _{EBO}	_	_	-100	nA	V _{EB} = - 5V, I _C = 0
ON CHARACTERISTICS (No	te 7)						
Collector-Emitter Saturation Voltage		V _{CE(sat)}		-0.35	-0.8	V	I _C = -2A, I _B = -0.2A
DC Current Gain	2DB1188P		82		180		
	2DB1188Q	h _{FE}	120	—	270	—	$V_{CE} = -3V$, $I_{C} = -0.5A$
	2DB1188R		180		390		
SMALL SIGNAL CHARACTE	RISTICS						
Current Gain-Bandwidth Product		f _T	_	120	_	MHz	V _{CE} = -5V, I _C = -0.1A, f = 30MHz
Output Capacitance		C _{obo}	_	20	_	pF	V _{CB} = -10V, f = 1MHz

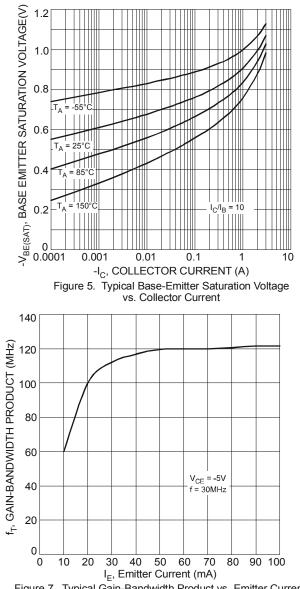
Notes: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

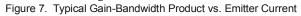


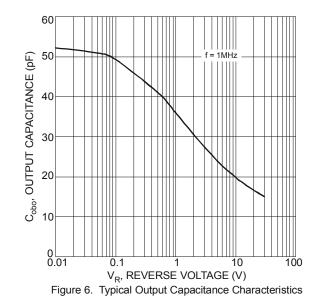




2DB1188P/Q/R



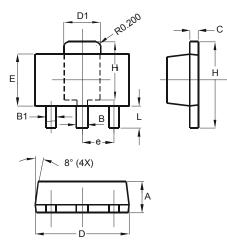






Package Outline Dimensions

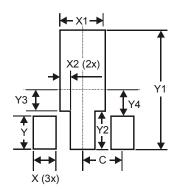
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
Н	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All C	All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500



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